July 2012



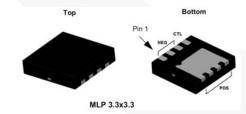
# FR014H5JZ (14mΩ, -30V) High-Side Reverse Bias / Reverse Polarity Protector With Integrated Over Voltage Transient Suppression

### Features

- Up to -30V Reverse-Bias Protection
- Nano Seconds of Reverse-Bias Blocking Response Time
- +32V 24-Hour "Withstand" Rating
- 14mΩ Typical Series Resistance at 5V
- Integrated TVS Over Voltage Suppression
- MLP 3.3x3.3 Package Size
- RoHs Compliant
- USB Tested and Compatible

### Applications

- USB 1.0, 2.0 and 3.0 Devices
- USB Charging
- Mobile Devices
- Mobile Medical
- POS Systems
- Toys
- Any DC Barrel Jack Powered Device
- Any DC Devices subject to Negative Hot Plug or Inductive Transients
- Automotive Peripherals



### Description

Reverse bias is an increasingly common fault event that may be generated by user error, improperly installed batteries, automotive environments, erroneous connections to third-party chargers, negative "hot plug" transients, inductive transients, and readily available negatively biased rouge USB chargers.

Fairchild circuit protection is proud to offer a new type of reverse bias protection devices. The FR devices are low resistance, series switches that, in the event of a reverse bias condition, shut off power and block the negative voltage to help protect downstream circuits.

The FR devices are optimized for the application to offer best in class reverse bias protection and voltage capabilities while minimizing size, series voltage drop, and normal operating power consumption.

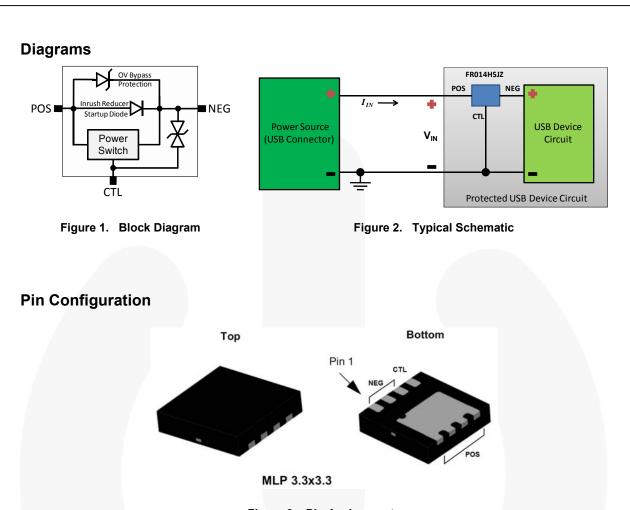
In the event of a reverse bias application, FR014H5JZ devices effectively provide a full voltage block and can easily protect -0.3V rated silicon.

From a power perspective, in normal bias, a  $14m\Omega$  FR device in a 1.5A application will generate only 21mV of voltage drop or 32mW of power loss. In reverse bias, FR devices dissipate less then  $20\mu W$  in a 16V reverse bias event. This type of performance is not possible with a diode solution.

Benefits extend beyond the device. Due to low power dissipation, not only is the device small, but heat sinking requirements and cost can be minimized as well.

## **Ordering Information**

1					
	Part Number	Top Mark	Package	Packing Method	
	FR014H5JZ	14H	8-Lead, Molded Leadless Package (MLP), Dual, 3.3mm Square	3000 on Tape & Reel; 13-inch Reel, 12mm Tape	





# **Pin Definitions**

Name Pin		Description
POS 5, 6, 7, 8 The positive terminal of the power source. Current flows into this pin during normal operation.		
CTL 4 The control pin of the device. A negative voltage to the POS pin turns the sw positive voltage turns the switch to a high-impedance state.		The control pin of the device. A negative voltage to the POS pin turns the switch on and a positive voltage turns the switch to a high-impedance state.
NEG	1, 2, 3	The positive terminal of the load circuit to be protected. Current flows out of this pin during normal operation.

# Absolute Maximum Ratings

Values are at T<sub>A</sub>=25°C unless otherwise noted.

Symbol			F	Parameter		Values	Unit
V+ <sub>MAX_OP</sub>	Steady-State Normal Operating $(V_{IN} = V + _{MAX_OP}, I_{IN} = 1.5A, Swi$				+25		
V+ <sub>24</sub>	24-Hour Nori and CTL Pins	mal Operating s (V <sub>IN</sub> = V+ <sub>24</sub> , I	Volta <sub>IN</sub> = 1	ge Withstand Capability be .5A, Switch On) <sup>(1)</sup>	tween POS	+32	V
V- MAX_OP	Steady-State Reverse Bias S $(V_{IN} = V_{-MAX_OP})$			doff Voltage between POS	-30		
I <sub>IN</sub>	Input Current	out Current Continuous <sup>(2)</sup> (see Figure 4)			9	А	
TJ	Operating Junction Temperature				150	°C	
Б	Dower Dissinction		$T_{\rm C} = 25^{\circ}{\rm C}$			36	- w
PD	Power Dissipation			= 25°C <sup>(2)</sup> (see Figure 4)	2.3		
IDIODE_CONT	Steady-State Diode Continuous Forward Current from POS to NEG <sup>(2)</sup> (see Figure 4)					2	
IDIODE_PULSE	Pulsed Diode Forward Current from POS to NEG (300µs Pulse) <sup>(2)</sup> (see Figure 5)					450	- A
	Human Body Model, JESD22-A114					8	
	Charged Devi			odel, JESD22-C101	2		
ESD		System Model, IEC61000-4-2		NEG is shorted to CTL and connected to GND	Contact	8	- kV
ESD					Air	15	ĸv
				No external connection	Contact	3	
				between NEG and CTL	Air	4	

#### Notes:

- 1. The V<sub>+24</sub> rating is NOT a survival guarantee. It is a statistically calculated survivability reference point taken on qualification devices, where the predicted failure rate is less than 0.01% at the specified voltage for 24 hours. It is intended to indicate the device's ability to withstand transient events that exceed the recommended operating voltage rating. Specification is based on qualification devices tested using accelerated destructive testing at higher voltages, as well as production pulse testing at the V<sub>+24</sub> level. Production device field life results may vary. Results are also subject to variation based on implementation, environmental considerations, and circuit dynamics. Systems should never be designed with the intent to normally operate at V<sub>+24</sub> levels. *Contact Fairchild Semiconductor for additional information*.
- 2. The device power dissipation and thermal resistance ( $R_{\theta}$ ) are characterized with device mounted on the following FR4 printed circuit boards, as shown in Figure 4 and Figure 5

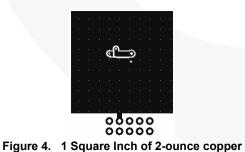




Figure 5. Minimum Pads of 2-ounce Copper

### **Thermal Characteristics**

$R_{\theta JC}$ Thermal Resistance, Junction to Case3.4 $R_{\theta JA}$ Thermal Resistance, Junction to Ambient <sup>(2)</sup> (see Figure 4)50		Symbol	Parameter	Value	Unit
R <sub>BJA</sub> Thermal Resistance, Junction to Ambient <sup>(2)</sup> (see Figure 4) 50	ſ	$R_{\theta JC}$	Thermal Resistance, Junction to Case	3.4	°C M
		$R_{\theta JA}$	Thermal Resistance, Junction to Ambient <sup>(2)</sup> (see Figure 4)	50	C/W

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# **Electrical Characteristics**

Values are at  $T_A = 25^{\circ}C$  unless otherwise noted.

Symbol	Para	meter	Conditions	Min.	Тур.	Max.	Unit
Positive Bias	Characteristics						
			V <sub>IN</sub> = +4V, I <sub>IN</sub> = 1.5A		18	23	
	Device Resistance, Switch On		V <sub>IN</sub> = +5V, I <sub>IN</sub> = 1.5A		14	19	mΩ
R <sub>ON</sub>			$V_{IN} = +5V, I_{IN} = 1.5A,$ T <sub>J</sub> = 125°C		20		
			V <sub>IN</sub> = +12V, I <sub>IN</sub> = 1.5A		11	14	
V <sub>ON</sub>	Input Voltage, V <sub>IN</sub> at POS, V <sub>POS</sub> , Rea Level at Given Cu	aches a Certain	I <sub>IN</sub> = 100mA, V <sub>POS</sub> - V <sub>NEG</sub> = 50mV, V <sub>CTL</sub> = 0V	2.0	2.4	3.0	V
$\Delta V_{ON}$ / $\Delta T_{J}$	Temperature Coer	fficient of V <sub>ON</sub>			-3.52		mV/°
V <sub>F</sub>	Diode Forward Vo	ltage	$V_{CTL} = V_{NEG}$ , $I_{DIODE} = 0.1A$ , Pulse width < 300µs	0.57	0.63	0.70	V
I <sub>BIAS</sub>	Bias Current Flow during Normal Bia		V <sub>POS</sub> = 5V, V <sub>CTL</sub> = 0V, No Load		30		nA
Negative Bias	Characteristics						
V- MAX_OP	Reverse Bias Brea	akdown Voltage	I <sub>IN</sub> = -250μA, V <sub>CTL</sub> = V <sub>NEG</sub> =0V			-30	V
ΔV- <sub>MAX_OP</sub> / ΔT <sub>J</sub>	Reverse Bias Breat Temperature Coer				22.5		mV/°
I-	Leakage Current f in Reverse-Bias C		V <sub>POS</sub> = -20V, V <sub>CTL</sub> = V <sub>NEG</sub> = 0V		1		μA
t <sub>RN</sub>	Time to Respond Condition	to Negative Bias	$V_{CTL}$ = 5V, $V_{POS}$ = 0V, $C_{LOAD}$ = 10µF, Reverse Bias Startup Inrush Current = 0.2A			50	ns
Integrated TV	S Performance						
Vz	Breakdown Voltag	je @ I⊤	I <sub>T</sub> = 1mA, 300µs Pulse	28.5	30	31.2	V
	Lookago Current f		V <sub>NEG</sub> = +25V, V <sub>CTL</sub> = 0V		1.5	10	
I <sub>R</sub>	Leakage Current f	IOIII NEG LO CTE	$V_{\text{NEG}}$ = -25V, $V_{\text{CTL}}$ = 0V		-1.5	-10	μA
	Max Pulse		V <sub>NEG</sub> > V <sub>CTL</sub>			0.8	
I <sub>PPM</sub>	Current from NEG to CTL		V <sub>NEG</sub> < V <sub>CTL</sub>			-0.9	A
	Clamping	IEC61000-4-5 8x20µs pulse	V <sub>NEG</sub> > V <sub>CTL</sub>		34		
Vc	Voltage form NEG to CTL at I <sub>PPM</sub>		V <sub>NEG</sub> < V <sub>CTL</sub>		-34		V
Dynamic Cha	racteristics						
Cı	Input Capacitance and CTL	between POS	V <sub>IN</sub> = -5V, V <sub>CTL</sub> = V <sub>NEG</sub> = 0V, f = 1MHz		2440		$\sim$
Cs	Switch Capacitance and NEG	ce between POS			564		pF
Co	Output Capacitane	ce between NEG			2526		
	Control Internal R				3.6	İ	Ω

### **Typical Characteristics**

T<sub>J</sub> = 25°C unless otherwise specified.

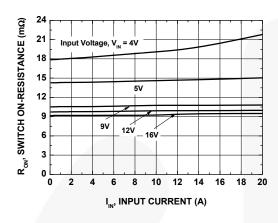


Figure 6. Switch On Resistance vs. Switch Current

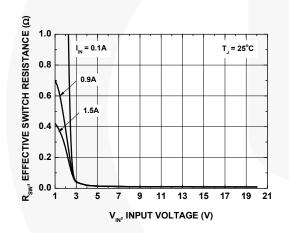
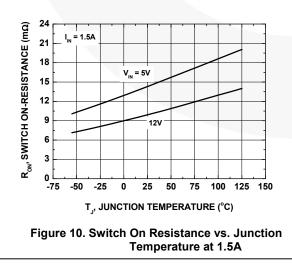
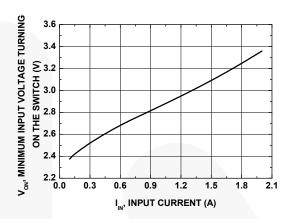
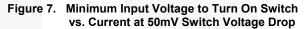


Figure 8. Effective Switch Resistance  $R_{SW}$  vs. Input Voltage  $V_{IN}$ 







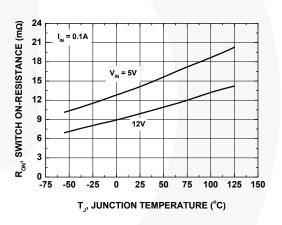
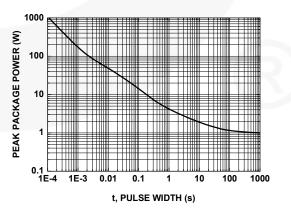


Figure 9. Switch On Resistance vs. Junction Temperature at 0.1A





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### **Typical Characteristics**

 $T_J$  = 25°C unless otherwise specified.

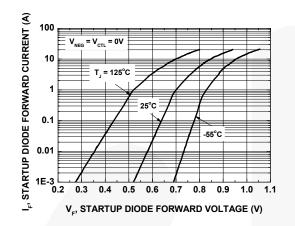
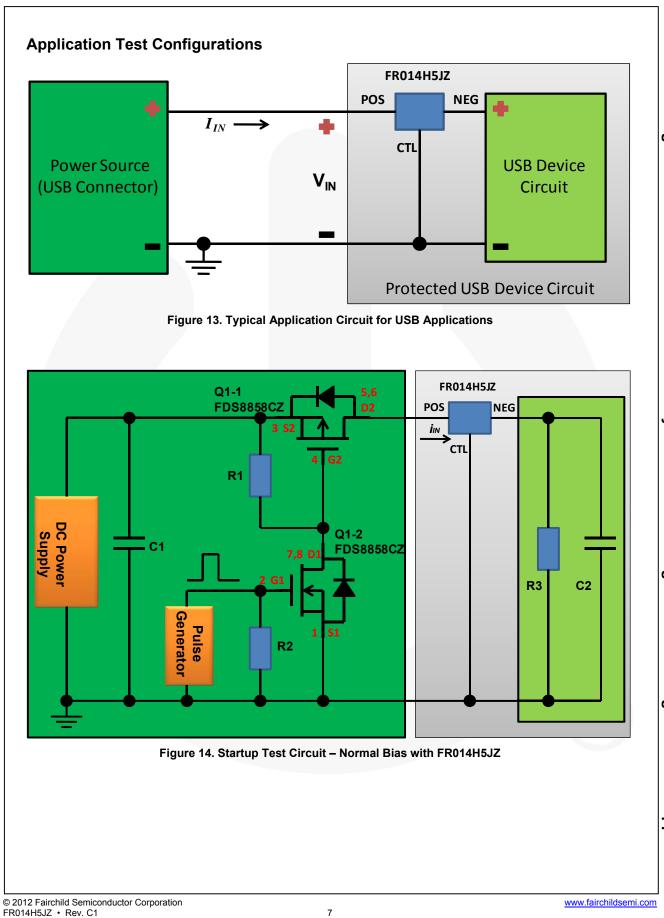
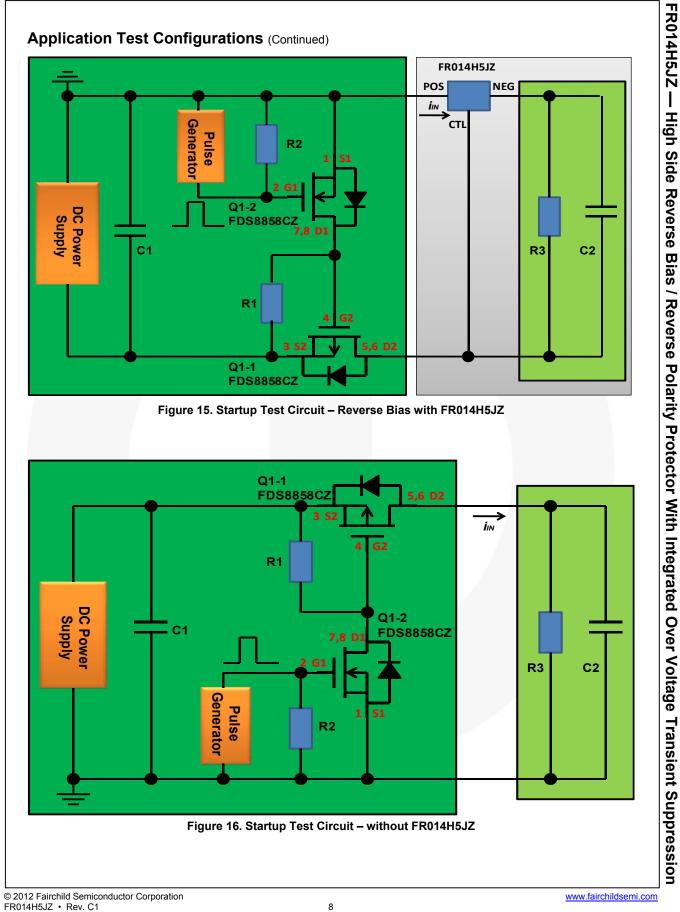
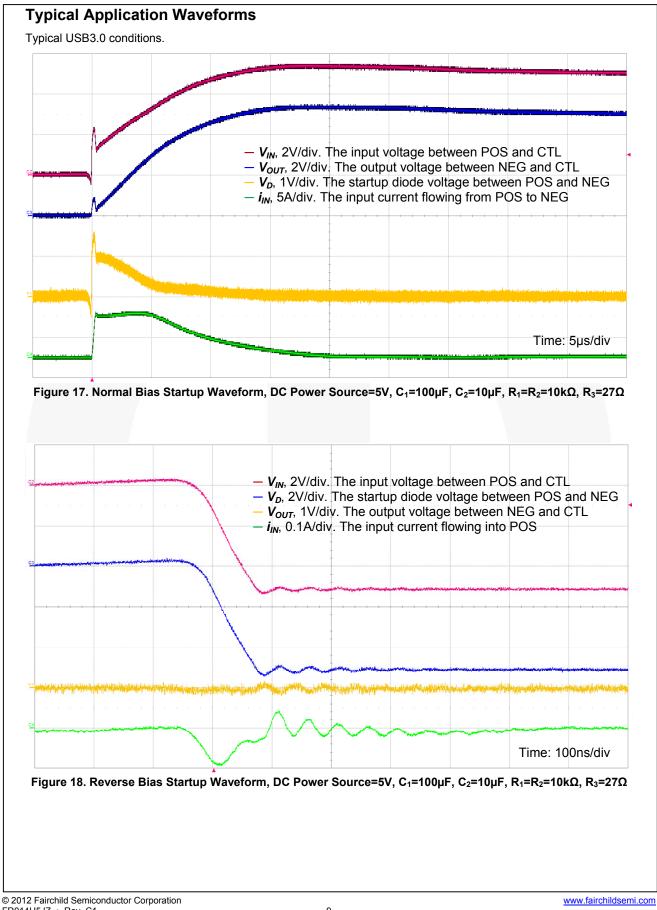


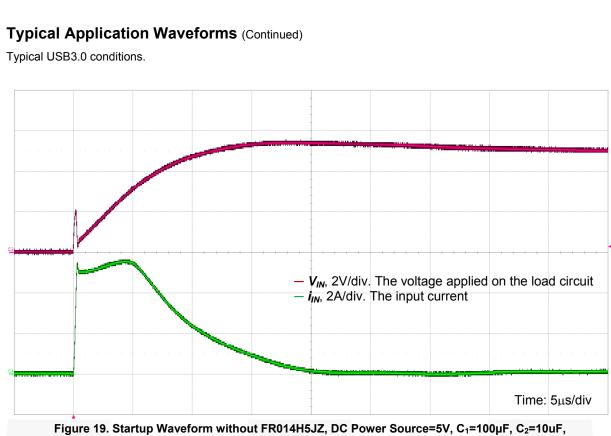
Figure 12. Startup Diode Current vs. Forward Voltage







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 $R_1 = R_2 = 10 k\Omega, R_3 = 27\Omega$ 

# Application Information

Figure 17 shows the voltage and current waveforms when a virtual USB3.0 device is connected to a 5V source. A USB application allows a maximum source output capacitance of  $C_1 = 120\mu$ F and a maximum device-side input capacitance of  $C_2 = 10\mu$ F plus a maximum load (minimum resistance) of  $R_3 = 27\Omega$ .  $C_1 = 100\mu$ F,  $C_2 = 10\mu$ F and  $R_3 = 27\Omega$  were used for testing.

When the DC power source is connected to the circuit (refer to Figure 13), the built-in startup diode initially conducts the current such that the USB device powers up. Due to the initial diode voltage drop, the FR014H5JZ effectively reduces the peak inrush current of a hot plug event. Under these test conditions, the input inrush current reaches about 6A peak. While the current flows, the input voltage increases. The speed of this input voltage increase depends on the time constant formed by the load resistance  $R_3$  and load capacitance  $C_2$ . The larger the time constant, the slower the input voltage increase. As the input voltage approaches a level equal to the protector's turn-on voltage,  $V_{ON}$ , the protector turns on and operates in Low-Resistance Mode as defined by  $V_{IN}$  and operating current  $I_{IN}$ .

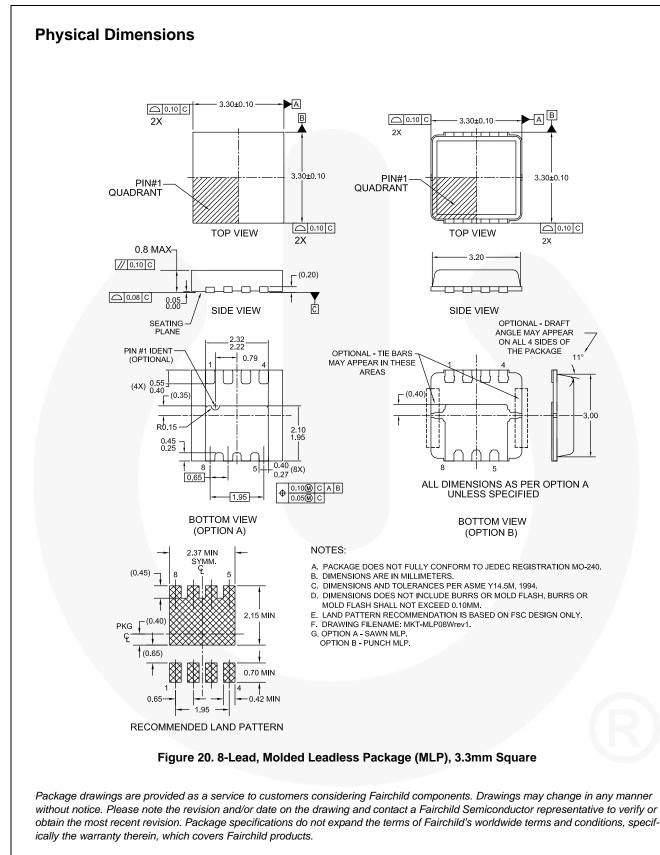
In the event of a negative transient, or when the DC power source is reversely connected to the circuit, the device blocks the flow of current and holds off the voltage, thereby protecting the USB device. Figure 18 shows the voltage and current waveforms when a virtual

USB3.0 device is reversely biased; the output voltage is near 0 and response time is less than 50ns.

Figure 19 shows the voltage and current waveforms when no reverse bias protection is implemented. In Figure 17, while the reverse bias protector is present, the input voltage,  $V_{IN}$ , and the output voltage,  $V_O$ , are separated and look different. When this reverse bias protector is removed,  $V_{IN}$  and  $V_O$  merge, as shown in Figure 19 as  $V_{IN}$ . This  $V_{IN}$  is also the voltage applied to the load circuit. It can be seen that, with reverse bias protection, the voltage applied to the load and the current flowing into the load look very much the same as without reverse bias protection.

#### **Benefits of Reverse Bias Protection**

The most important benefit is to prevent accidently reverse-biased voltage from damaging the USB load. Another benefit is that the peak startup inrush current can be reduced. How fast the input voltage rises, the input/output capacitance, the input voltage, and how heavy the load is determine how much the inrush current can be reduced. In a 5V USB application, for example, the inrush current can be 5% - 20% less with different input voltage rising rate and other factors. This can offer a system designer the option of increasing  $C_2$  while keeping "effective" USB device capacitance down.



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